A Product Line of Diodes Incorporated | LITE-ON SEMICONDUCTOR

S08xxA SERIES

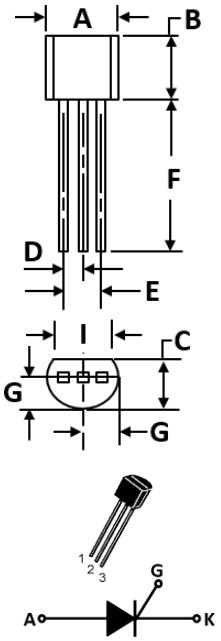
Sensitive Gate Sillicon Controlled Rectifiers
Reverse Blocking Thyristors

SCRs
0.8 AMPERES RMA 600 VOLTS

FEATURES

- Sensitive Gate Allows Triggering by Microcontrollers and Other Logic Circuits
- Blocking Voltage to 600 Volts
- On-State Current Rating of 0.8 Amperes RMS at 80°C
- High Surge Current Capability — 10 Amperes
- Minimum and Maximum Values of IGT, VGT and IH Specified for Ease of Design
- Immunity to dV/dt — 20 V/us Minimum at T_J=110°C
- Glass-Passivated Surface for Reliability and Uniformity
- Pb-Free Package
- TO-92
  - **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- Available in “Green” Package: TO-92
  - **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
  - **Halogen and Antimony Free. “Green” Device (Note 3)**

TO-92 (TO-226AA)



TO-92		
Dim.	Min.	Max.
A	4.45	4.70
B	4.32	5.33
C	3.18	4.19
D	1.15	1.39
E	2.42	2.66
F	12.7	--
G	2.04	2.66
I	3.43	--
All Dimensions in millimeter		

PIN ASSIGNMENT	
1	Cathode
2	Gate
3	Anode

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

CHARACTERISTICS	SYMBOL	VALUE	UNIT
Peak Repetitive Off– State Voltage (TJ= -40 to 110°C, Sine Wave, 50 to 60 Hz; Gate Open) S08U25600A S08U50600A S08M02600A	V_{DMS} V_{RRM}	600	V
On-State RMS Current (TC = 80°C) 180° Conduction Angles	$I_{T(RMS)}$	0.8	A
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave, 60 Hz, T_J = 25°C)	I_{TSM}	10	A
Circuit Fusing Consideration (t = 8.3 ms)	I^2t	0.415	A^2s
Forward Peak Gate Power (TA = 25℃, Pulse Width 1.0 us)	P_{GM}	0.1	W
Forward Average Gate Power (TA = 25℃, t = 8.3 ms)	$P_{GM(AV)}$	0.01	W
Forward Peak Gate Current (TA = 25℃, Pulse Width≦1.0 us)	I_{GM}	1.0	A
Reverse Peak Gate Voltage (TA = 25℃, Pulse Width≦1.0 ms)	V_{GRM}	5	V
Operating temperature range @ Rate V_{RRM} and V_{DRM}	T_J	-40 to +110	°C
Storage temperature range	T_{STG}	-40 to +150	°C

REV-4, Oct-2021, KTXDG18

Note:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated’s definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded

RATING AND CHARACTERISTIC CURVES
S08xxA SERIES

THERMAL CHARACTERISTICS

CHARACTERISTICS	SYMBOL	VALUE	UNIT
Thermal Resistance - Junction to Case - Junction to Case	RthJC RthJA	75 150	°C/W
Maximum Lead Temperature for Soldering Purposes 1/16" from Case for 10 Seconds	T_L	260	°C

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

OFF CHARACTERISTICS

CHARACTERISTICS		SYMBOL	MAX	UNIT
Peak Repetitive Forward or Reverse Blocking Current (VD=Rated VDRM and VRRM; RGK =1K Ohms)	T_J = 25℃ T_J = 110℃	I_{DRM} I_{RRM}	10 100	μA
Maximum Lead Temperature for Soldering Purposes 1/16" from Case for 10 Seconds		T_L	260	°C

ON CHARACTERISTICS

CHARACTERISTICS		SYMBOL	MAX	UNIT
Peak Forward On-State Voltage (ITM= ± 1.6A Peak, Pulse Width≦ 1.0ms, Duty Cycle≦ 1%)		V_{TM}	1.7	V
Gate Trigger Current(VD= 7.0 Vdc,RL=100 Ohms) (1)	S08U25600A S08U50600A S08M02600A	I_{GT}	25 50 200	μA
Holding Current(VD= 7.0 Vdc, Intitiating Current = 20mA	T_J = 25℃ T_J = -40℃	I_H	5 10	mA
Gate Trigger Voltage(VD= 7.0 Vdc,RL=100 Ohms) (1)	T_J = 25℃ T_J =-40℃	V_{GT}	10 100	V
Latch Current(VD= 7.0 Vdc, RL 100 Ohms)	T_J = 25℃ T_J = -40℃	I_L	10 100	mA

DANAMIC CHARACTERISTICS

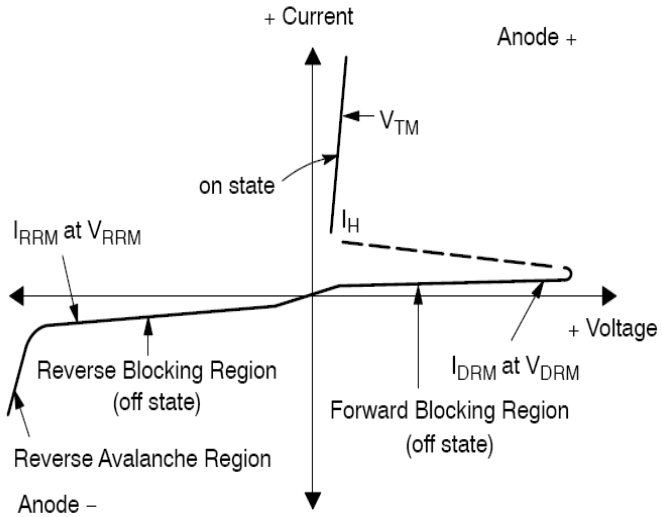
CHARACTERISTICS		SYMBOL	MIN.	UNIT
Critical Rate of Rise of Off-State Voltage (V_D=Rated V_{DRM} ,Exponential Waveform, PGK=1K Ohms, TJ=110℃)	T_J = 110℃	dv/dt	20	V/us

(1) RGK current is not included in measurement

RATING AND CHARACTERISTIC CURVES
S08xxA SERIES

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Off State Forward Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Off State Reverse Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Peak on State Voltage
I_H	Holding Current



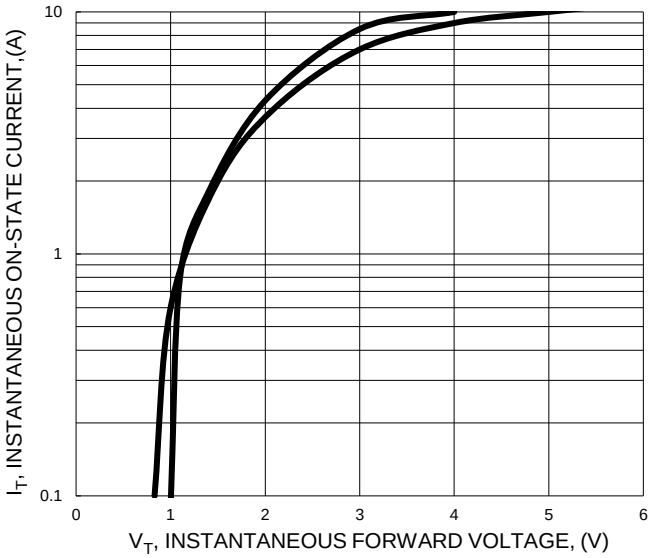


FIG.1- ON-STATE CHARACTERISTICS

RATING AND CHARACTERISTIC CURVES
S08xxA SERIES

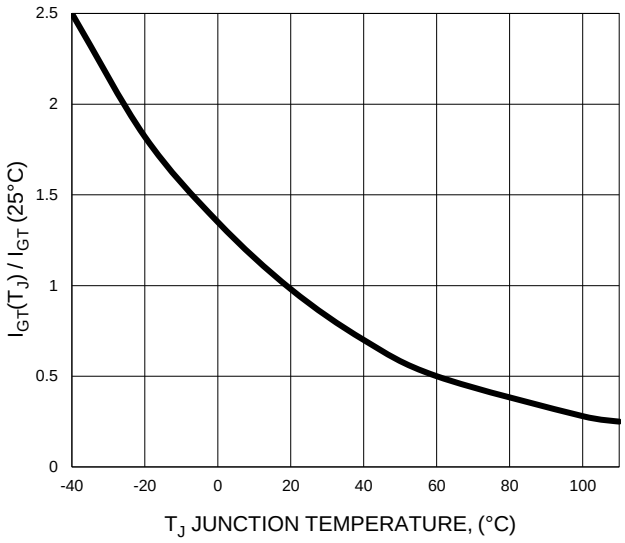


FIG.2- I_{GT}(TJ) / I_{GT}(25°C) VERSUS T_J

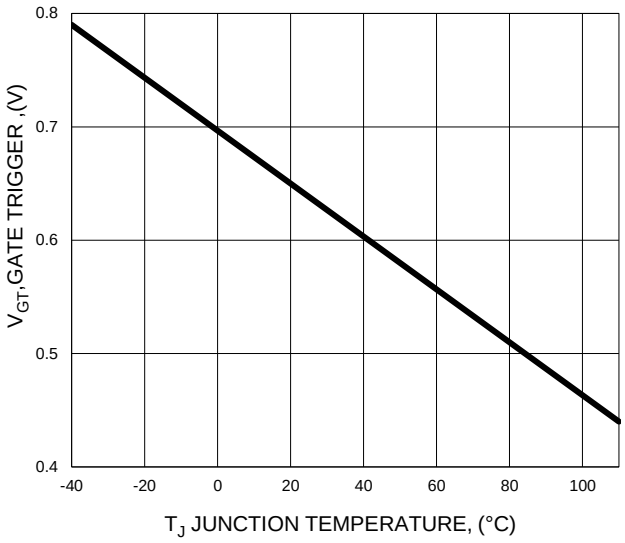


FIG.3- TYPICAL V_{GT} VERSUS T_J

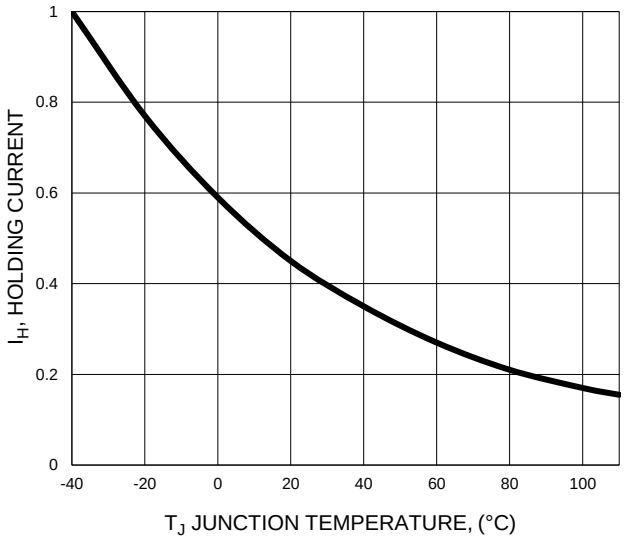


FIG.4- TYPICAL I_H VERSUS T_J

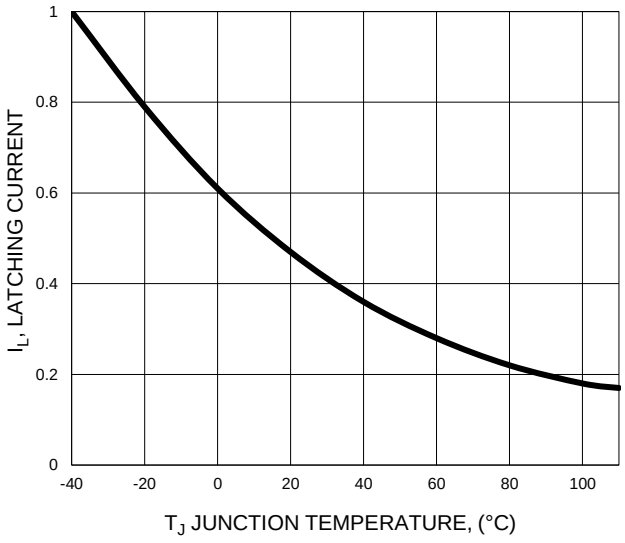


FIG.5- TYPICAL I_L VERSUS T_J

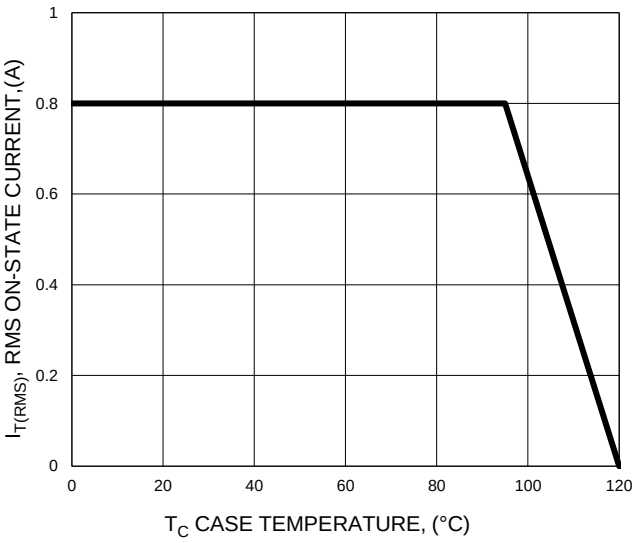


FIG.6- ON-STATE CURRENT DERATING CURVE

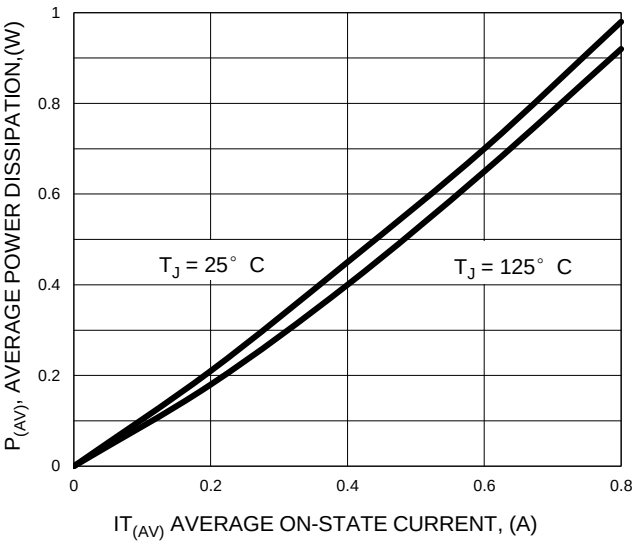
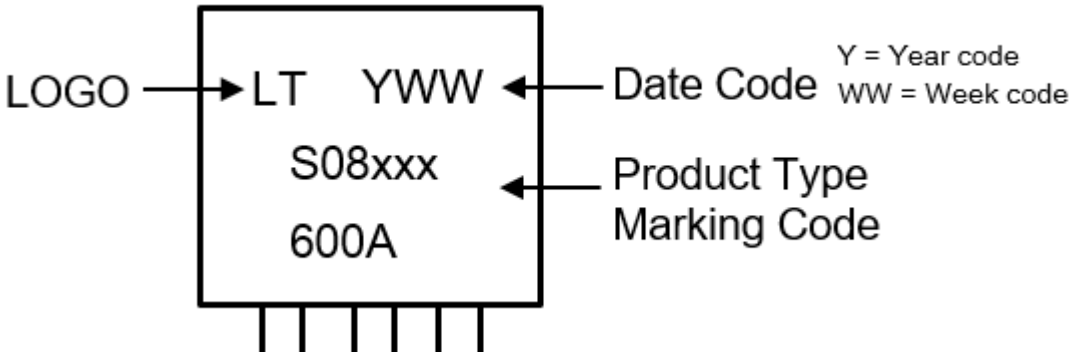


FIG.7- POWERE DISSIPATION VERSUS I_T

Ordering Information :

Part Number	Package	Packing	
		Qty.	Carrier
S08U50600A	TO-92	2000pcs	Reel
S08U25600A	TO-92	1000pcs	Bulk
S08M02600A	TO-92	1000pcs	Reel
S08M02600A-BU	TO-92	1000pcs	Bulk
S08M02600A_HF	TO-92	1000pcs	Reel

Marking Information :



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